

1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- Low reverse recovery current
- Low leakage current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

3. Applications

- Half-bridge/full-bridge switched-mode power supplies
- Continuous Current Mode (CCM) Power Factor Correction (PFC)

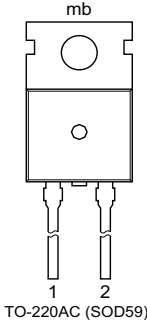
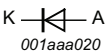
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute maximum rating							
V _{RRM}	repetitive peak reverse voltage		600			V	
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 130 °C; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3	8			A	
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 130 °C; square-wave pulse	16			A	
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4	91			A	
		t _p = 8.3 ms; T _{j(init)} = 25 °C; sine-wave pulse	100			A	
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 8 A; T _j = 125 °C; Fig. 6		-	1.5	1.9	V
Dynamic characteristics							
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 200 A/μs; T _j = 25 °C; Fig. 7		-	12	18	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYC8-600P	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59

7. Marking

Table 4. Marking codes

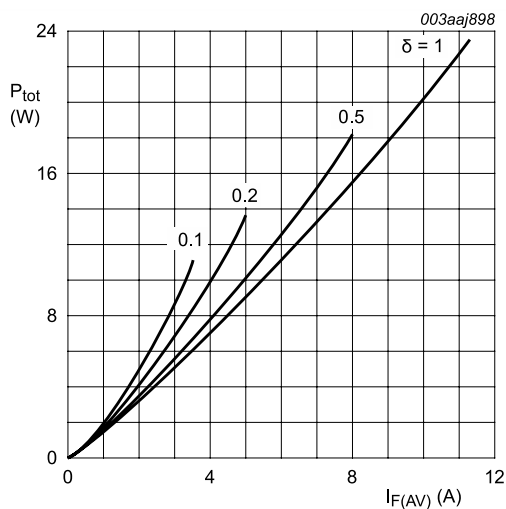
Type number	Marking codes
BYC8-600P	BYC8-600P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

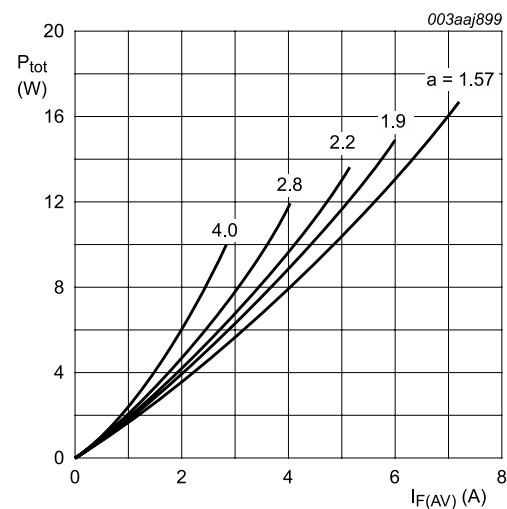
Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $T_{mb} \leq 130\text{ }^{\circ}\text{C}$; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3	8	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 130\text{ }^{\circ}\text{C}$; square-wave pulse	16	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sine-wave pulse; Fig. 4	91	A
		$t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sine-wave pulse	100	A
T_{stg}	storage temperature		-65 to 175	$^{\circ}\text{C}$
T_j	junction temperature		175	$^{\circ}\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 1.581\text{ V}; R_s = 0.043\text{ }\Omega$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 1.581\text{ V}; R_s = 0.043\text{ }\Omega$$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

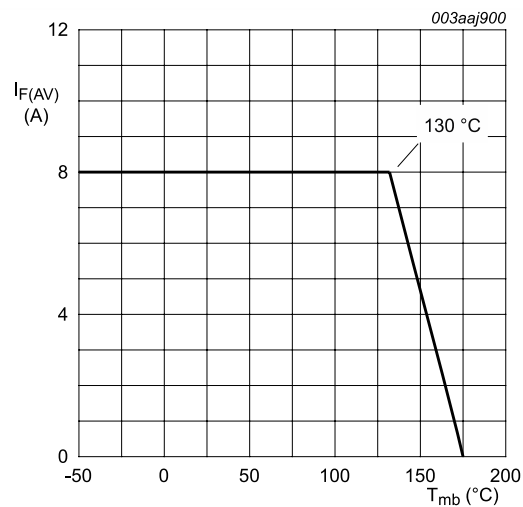


Fig. 3. Average forward current as a function of mounting base temperature; maximum values

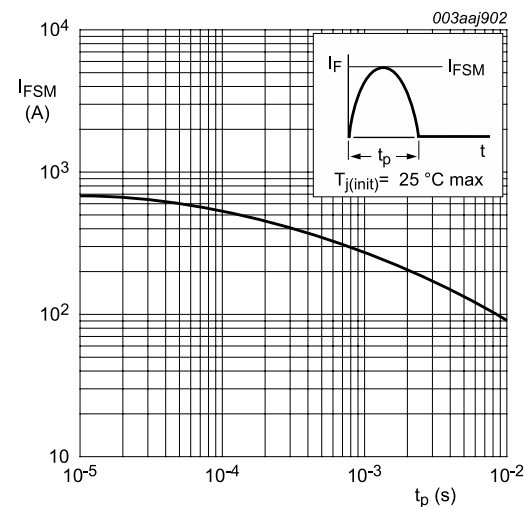


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

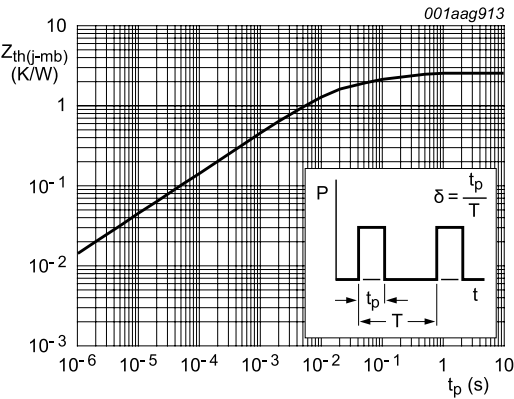
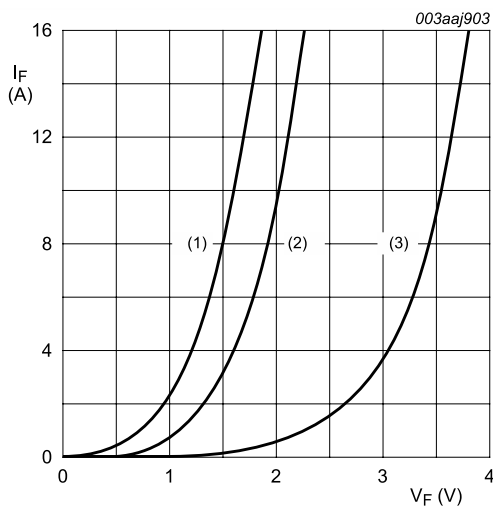


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse width

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 8 A; T _J = 25 °C; Fig. 6		-	-	3.4	V
		I _F = 8 A; T _J = 125 °C; Fig. 6		-	1.5	1.9	V
		I _F = 8 A; T _J = 150 °C		-	1.4	-	V
I _R	reverse current	V _R = 600 V; T _J = 25 °C		-	-	20	μA
		V _R = 600 V; T _J = 125 °C		-	-	200	μA
Dynamic characteristics							
Q _r	recovered charge	I _F = 8 A; V _R = 200 V; di _F /dt = 200 A/μs; T _J = 25 °C; Fig. 7		-	17	-	nC
		I _F = 8 A; V _R = 200 V; di _F /dt = 200 A/μs; T _J = 125 °C; Fig. 7		-	90	-	nC
t _{rr}	reverse recovery time	I _F = 8 A; V _R = 400 V; di _F /dt = 500 A/μs; T _J = 25 °C; Fig. 7		-	19	-	ns
		I _F = 1 A; V _R = 30 V; di _F /dt = 200 A/μs; T _J = 25 °C; Fig. 7		-	12	18	ns
I _{RM}	peak reverse recovery current	I _F = 8 A; V _R = 200 V; di _F /dt = 200 A/μs; T _J = 25 °C; Fig. 7		-	-	2.2	A
		I _F = 8 A; V _R = 200 V; di _F /dt = 200 A/μs; T _J = 125 °C; Fig. 7		-	-	6	A



- (1) $T_J = 125\text{ °C}$; typical values
 (2) $T_J = 125\text{ °C}$; maximum values
 (3) $T_J = 25\text{ °C}$; maximum values
 $V_o = 1.581\text{ V}; R_s = 0.043\text{ }\Omega$

Fig. 6. Forward current as a function of forward voltage

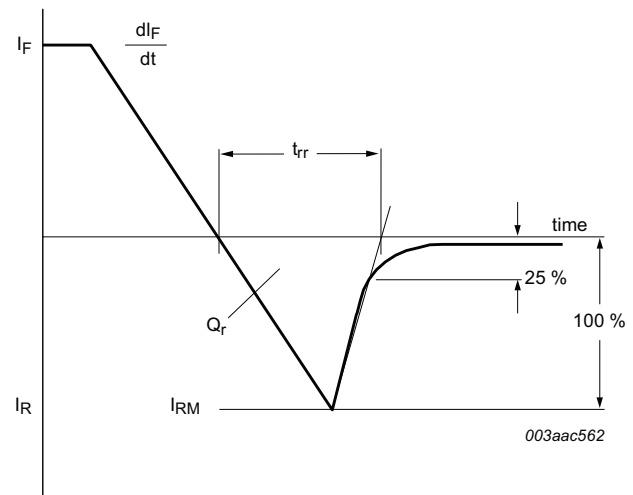
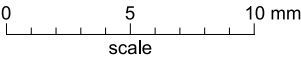
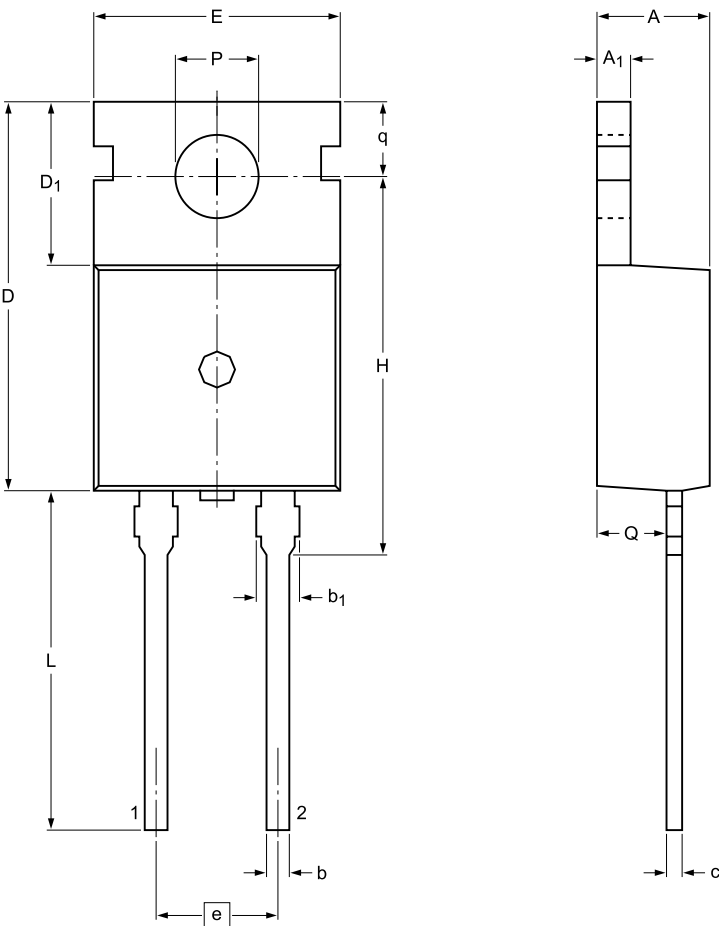


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC

SOD59



Dimensions

Unit	A	A ₁	b	b ₁ (1)	c	D	D ₁	E	e	H	L	P	Q	q
max	4.7	1.40	0.95	1.7	0.65	15.8	6.8	10.30	5.08	16.25	15.0	3.80	2.6	2.9
nom									(REF)					
min	4.3	1.15	0.70	1.3	0.45	15.6	6.4	9.65		15.70	12.5	3.65	2.2	2.7

Note

1. Protruded dambar are included in the dimension.

sod059_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOD59	2-lead TO-220AC					09-08-25 12-11-27

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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